#### **Current and Resistance**

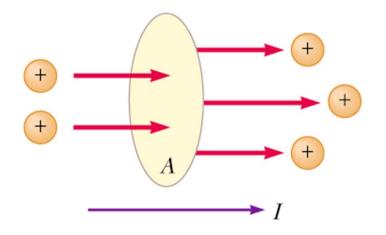
- Putting electrons in motion
- Electron movement through conductors
- Resistivity and Resistance Ohm's Law
- Electrical Power

#### Current

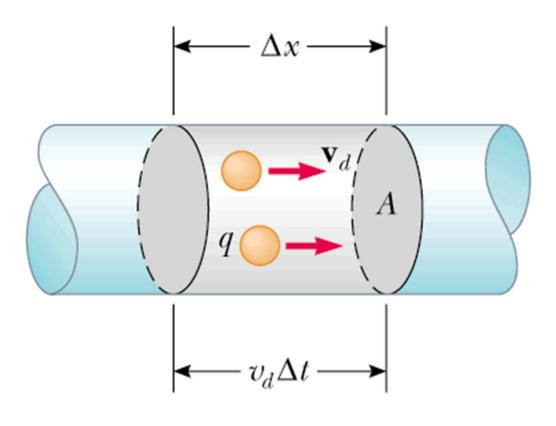
- Current is the flow rate of charges through a surface area.
- The direction of the current is the direction of the flow of positive charges.

$$I_{av} = \frac{\Delta Q}{\Delta t}$$

$$I(t) = \frac{dQ}{dt} \qquad (C/s = Amperes)$$



# Microscopic Model



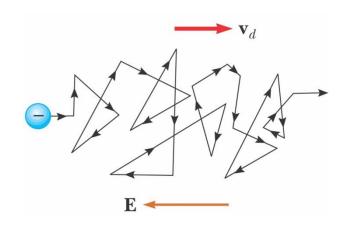
 $V_d$ : Drift Velocity

$$\Delta Q = (nV)q$$

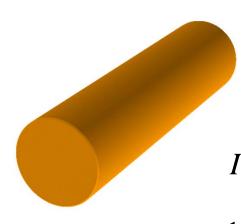
$$\Delta Q = (nA\Delta x)q$$

$$\Delta Q = (nAv_d \Delta t)q$$

$$I_{av} = \frac{\Delta Q}{\Delta t} = nqv_d A$$



## **Drift Speed In Copper Wire**



A = 3.31 x 
$$10^{-6}$$
 m<sup>2</sup>  
I = 10 A  
 $\rho_{Cu}$  = 8.92 g/cm<sup>3</sup>

$$I_{av} = \frac{\Delta Q}{\Delta t} = nqv_d A$$

$$10A = nv_d \left( 1.6 \times 10^{-19} \right) \left( 3.31 \times 10^{-6} \right)$$

$$V = \frac{m}{\rho} = \frac{63.5}{8.92} = 7.12cm^{3} / mol$$

$$n = \frac{N_{A}}{V} = \frac{6.02 \times 10^{23}}{7.12} = 8.46 \times 10^{22} el / cm^{3} = 8.46 \times 10^{28} el / m^{3}$$

$$v_d = \frac{10}{(1.6 \times 10^{-19})(3.31 \times 10^{-6})(8.46 \times 10^{28})} = 2.23 \times 10^{-4} \, \text{m/s}$$

m = 63.5 g/mol  $N_A = 6.02 \times 10^{23}$  at/mol 1 electron per Cu atom

#### Ohm's Law

$$J = \frac{I}{A} = nqv_d$$

 $J = \frac{I}{A} = nqv_d$  (for a uniform current perpendicular to the cross-section)

**Current Density:** 

$$\mathbf{J} = nq\mathbf{v}_d$$

General vector definition

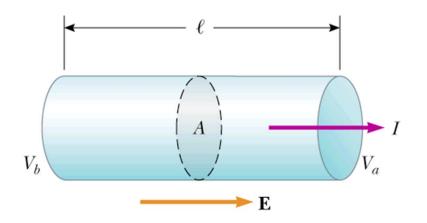
In some materials, the field applied and the current density are proportional.

Ohm's Law: 
$$\mathbf{J} = \sigma \mathbf{E}$$

σ: conductivity

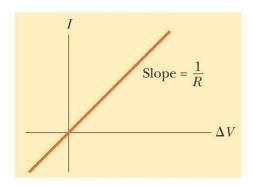
Most metals obey Ohm's Law

## Resistance

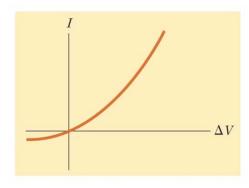


$$\Delta V = El = \frac{J}{\sigma}l = \left(\frac{l}{\sigma A}\right)I$$

$$R = \frac{l}{\sigma A} \equiv \frac{\Delta V}{I} \qquad (V/A = \Omega)$$



Metal



Semiconductor diode

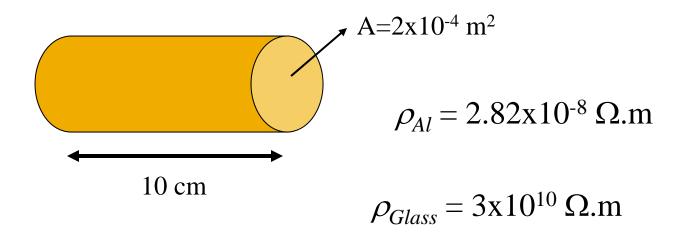
# Resistivity

- Resistivity is the inverse of conductivity.
- Both are intrinsic properties of the material.
- Resistance is a also a function of the shape and size of the device.

$$\rho = \frac{1}{\sigma} \qquad R = \rho \frac{l}{A}$$

Material	$ ho$ ( $\Omega$ .m)
Copper	1.7x10 <sup>-8</sup>
Gold	2.44x10 <sup>-8</sup>
Aluminum	2.82x10 <sup>-8</sup>
Silicon	640
Rubber	~10 <sup>13</sup>

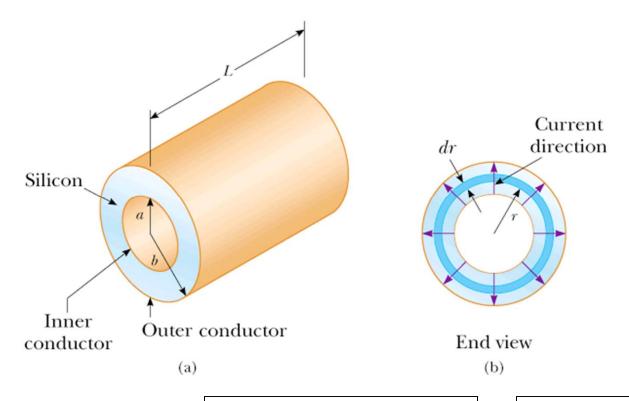
### Resistance of a Conductor



$$R_{Al} = \rho_{Al} \frac{l}{A} = \left(2.82 \times 10^{-8} \right) \left(\frac{0.1}{2 \times 10^{-4}}\right) = 1.41 \times 10^{-5} \Omega$$

$$R_{Glass} = \rho_{Glass} \frac{l}{A} = \left(3 \times 10^{10} \right) \left( \frac{0.1}{2 \times 10^{-4}} \right) = 1.5 \times 10^{13} \Omega$$

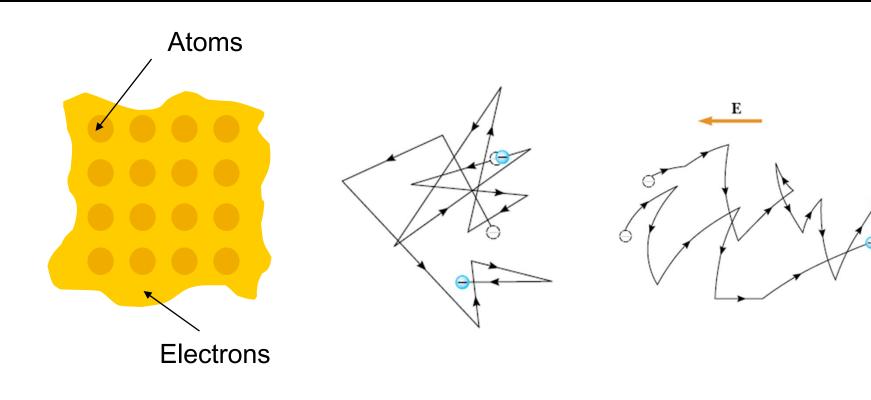
# Radial Resistance of a Coaxial Cable



$$R = \frac{\rho}{2\pi L} \ln\left(\frac{b}{a}\right)$$

$$C = \frac{L}{2k_e \ln\left(\frac{b}{a}\right)}$$

### A Model for Electrical Conduction: The Drude Model



A regular array of atoms surrounded by a "cloud" of free electrons

Random movement under zero field

Random movement modified by a field

#### **Drude Model**

$$\mathbf{F} = q\mathbf{E} = m_e \mathbf{a}$$

$$\mathbf{a} = \frac{q\mathbf{E}}{m_e}$$

$$\mathbf{v}_f = \mathbf{v}_i + \mathbf{a}t = \mathbf{v}_i + \frac{q\mathbf{E}}{m_e}t$$

Now take the average over all times. Then  $\mathbf{v}_i = 0$  (random movement),

$$\overline{\mathbf{v}}_f = \mathbf{v}_d = \frac{q\mathbf{E}}{m_e} \overline{t} = \frac{q\mathbf{E}}{m_e} \tau$$

, where au is the mean time between collisions

$$J = nqv_d = \frac{nq^2E}{m_e}\tau$$

$$J = \sigma E$$

$$\sigma = \frac{nq^2\tau}{m_e}$$

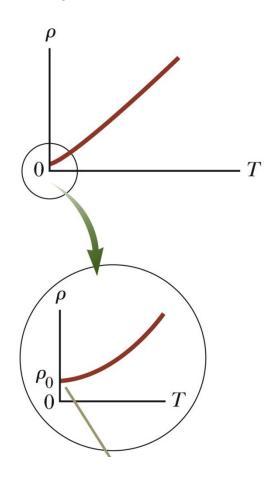
$$\rho = \frac{m_e}{nq^2\tau}$$

$$l = \tau \cdot v_d$$

is the mean free path

# Resistivity and Temperature

Resistivity in metals is linear with temperature over a limited range



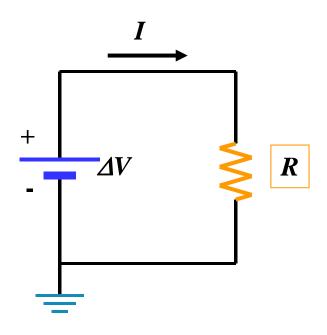
$$\rho = \rho_0 \left[ 1 + \alpha \left( T - T_0 \right) \right]$$

$$R = R_0 \left[ 1 + \alpha \left( T - T_0 \right) \right]$$

 $\alpha$ : temperature coefficient of resistivity

$$\alpha = \frac{1}{\rho_0} \frac{\Delta \rho}{\Delta T} \quad (C^{-1})$$

#### **Electrical Power**



$$\Delta U_{battery} = \Delta Q \Delta V$$

$$\Delta U_{resistor}(heat) = \Delta U_{battery}$$

$$\frac{\Delta U}{\Delta t} = \frac{\Delta Q \Delta V}{\Delta t} = I \Delta V$$

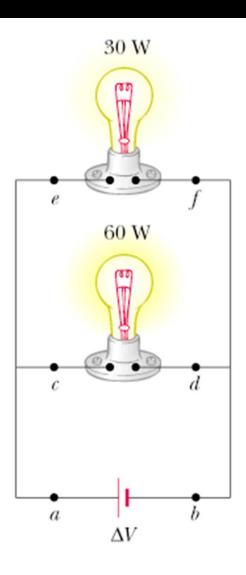
$$\mathcal{P} = I \Delta V$$

Electrical Power V.A = Watts(W)

$$\mathscr{P} = I^2 R = \frac{\left(\Delta V\right)^2}{R}$$

Power Dissipated on a Resistor

# Rank the Currents



$$I_a = I_b$$

$$I_c = I_d$$

$$I_e = I_f$$

$$I_a = I_b > I_c = I_d > I_e = I_f$$

$$I_a = I_c + I_e$$

$$\mathcal{P}_{60W} > \mathcal{P}_{30W}$$

$$I_c > I_e$$

## Summary

- Current is the net rate of charge flow.
- Electrons move at the drift velocity.
- Resistance is the ratio of voltage applied to current. The ratio is linear for most metals.
- Resistivity is a material property.
- Electrical energy will be converted to thermal energy on a resistor. The rate of conversion is the power.

#### For Next Class

- Reading Assignment
  - Chapter 28 Direct Current Circuits
- WebAssign: Assignment 5